



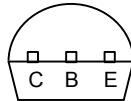
Micro Commercial Components
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MPSA55 MPSA56

Features

- Capable of 1.5Watts of Power Dissipation.
- Collector-current 500mA
- Collector-base Voltage 80V
- Operating and storage junction temperature range: -55°C to +150°C

Pin Configuration
Bottom View



PNP Silicon Amplifier Transistor

Maximum Ratings

Symbol	Rating	Rating	Unit
V_{CE0}	Collector-Emitter Voltage	80	V
V_{CBO}	Collector-Base Voltage	80	V
V_{EBO}	Emitter-Base Voltage	4.0	V
I_C	Collector Current Continuous	500	mA
P_D	Total Device Dissipation @ $T_A=25^\circ\text{C}$ Derate above 25°C	625 5.0	mW mW/°C
P_D	Total Device Dissipation @ $T_A=25^\circ\text{C}$ Derate above 25°C	1.5 12	W mW/°C
T_J	Junction Temperature	-55 to +150	°C
T_{STG}	Storage Temperature	-55 to +150	°C

Electrical Characteristics @ 25°C Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
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OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ⁽¹⁾ ($I_C=1.0\text{mA}$, $I_B=0$)	MPSA55 MPSA56	60 80	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=100\mu\text{A}$, $I_C=0$)		4.0	Vdc
I_{CES}	Collector Cutoff Current ($V_{CE}=60\text{Vdc}$, $I_B=0$)		0.1	μA
I_{CBO}	Collector Cutoff Current ($V_{CB}=60\text{Vdc}$, $I_E=0$) ($V_{CB}=80\text{Vdc}$, $I_E=0$)	MPSA55 MPSA56	0.1 0.1	μA

ON CHARACTERISTICS⁽¹⁾

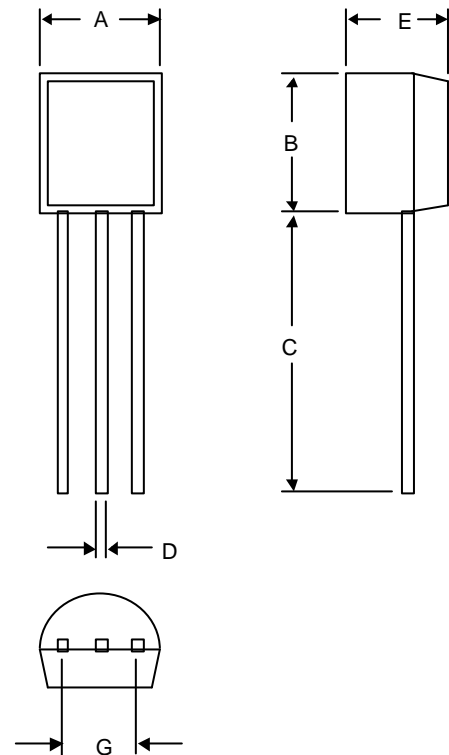
$h_{FE(1)}$	DC Current Gain ($I_C=10\text{mA}$, $V_{CE}=1.0\text{Vdc}$)		100	
$h_{FE(2)}$	DC Current Gain ($I_C=100\text{mA}$, $V_{CE}=1.0\text{Vdc}$)		100	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=100\text{mA}$, $I_B=10\text{mA}$)		0.25	Vdc
$V_{BE(on)}$	Base-Emitter Saturation Voltage ($I_C=100\text{mA}$, $V_{CE}=1.0\text{Vdc}$)		1.2	Vdc

SMALL-SIGNAL CHARACTERISTICS

f_T	Current Gain – Bandwidth Product ⁽³⁾ ($I_C=100\text{mA}$, $V_{CE}=1.0\text{Vdc}$, $f=100\text{MHz}$)	MPSA55 MPSA56	50	MHz
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1. Pulse Test: Pulse Width<300 μs , Duty Cycle<2.0%
2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

TO-92



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.175	.185	4.45	4.70	
B	.175	.185	4.46	4.70	
C	.500	---	12.7	---	
D	.016	.020	0.41	0.63	
E	.135	.145	3.43	3.68	
G	.095	.105	2.42	2.67	